

MOS FIELD EFFECT TRANSISTOR 2SK3294

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3294 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for high voltage applications such as DC/DC converter, actuator driver.

FEATURES

- Gate voltage rating ±30 V
- Low on-state resistance $R_{DS(on)} = 160 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, I_D = 10 \text{ A})$
- Low input capacitance $C_{iss} = 1500 \text{ pF TYP}. (V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V})$
- Avalanche capability rated
- Built-in gate protection diode
- Surface mount device available

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage ($V_{GS} = 0 V$)	VDSS	250	V
Gate to Source Voltage ($V_{DS} = 0 V$)	V _{GSS}	±30	V
Drain Current (DC) (Tc = 25°C)	D(DC)	±20	А
Drain Current (Pulse) ^{Note1}	D(pulse)	±60	А
Total Power Dissipation ($T_c = 25^{\circ}C$)	Ρτι	100	W
Total Power Dissipation ($T_A = 25^{\circ}C$)	P _{T2}	1.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	AS	20	А
Single Avalanche Energy Note2	Eas	150	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting $T_{ch} = 25^{\circ}C$, $V_{DD} = 150$ V, $R_G = 25 \Omega$, $V_{GS} = 20$ V \rightarrow 0 V

ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SK3294	TO-220AB		
2SK3294-S	TO-262		
2SK3294-ZJ	TO-263(MP-25ZJ)		



(TO-220AB)

(TO-262)



(TO-263)



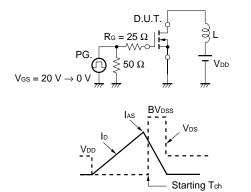
The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

ELECTRICAL CHARACTERISTICS (TA = 25°C)

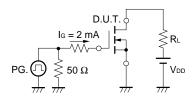
Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Zero Gate Voltage Drain Current	IDSS	Vds = 250 V, Vgs = 0 V			100	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 30 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Gate Cut-off Voltage	VGS(off)	V _{DS} = 10 V, I _D = 1 mA	2.5		4.5	V
Forward Transfer Admittance	yfs	Vds = 10 V, Id = 10 A	6.0			S
Drain to Source On-state Resistance	RDS(on)	Vgs = 10 V, Id = 10 A		120	160	mΩ
Input Capacitance	Ciss	Vbs = 10 V		1500		pF
Output Capacitance	Coss	Vgs = 0 V		360		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		220		pF
Turn-on Delay Time	td(on)	Vdd = 125 V , Id = 10 A		24		ns
Rise Time	tr	Vgs = 10 V		78		ns
Turn-off Delay Time	td(off)	$R_G = 10 \Omega$		110		ns
Fall Time	tr			60		ns
Total Gate Charge	QG	Vdd = 200 V		57		nC
Gate to Source Charge	Q _{GS}	Vgs = 10 V		8		nC
Gate to Drain Charge	QGD	ID = 20 A		36		nC
Body Diode Forward Voltage	VF(S-D)	IF = 20 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 20 A, VGS = 0 V		340		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/µs		2.1		μC

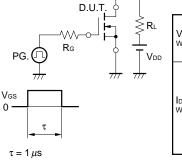
TEST CIRCUIT 1 AVALANCHE CAPABILITY

TEST CIRCUIT 2 SWITCHING TIME

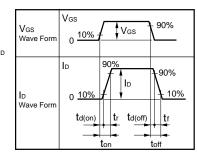


TEST CIRCUIT 3 GATE CHARGE

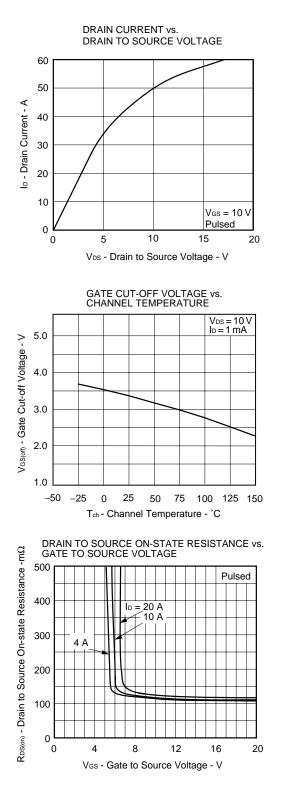


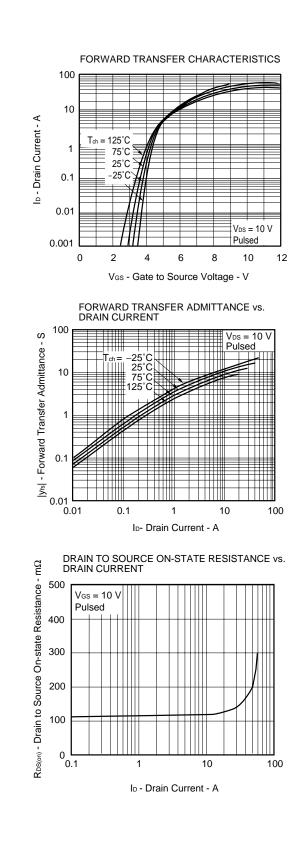


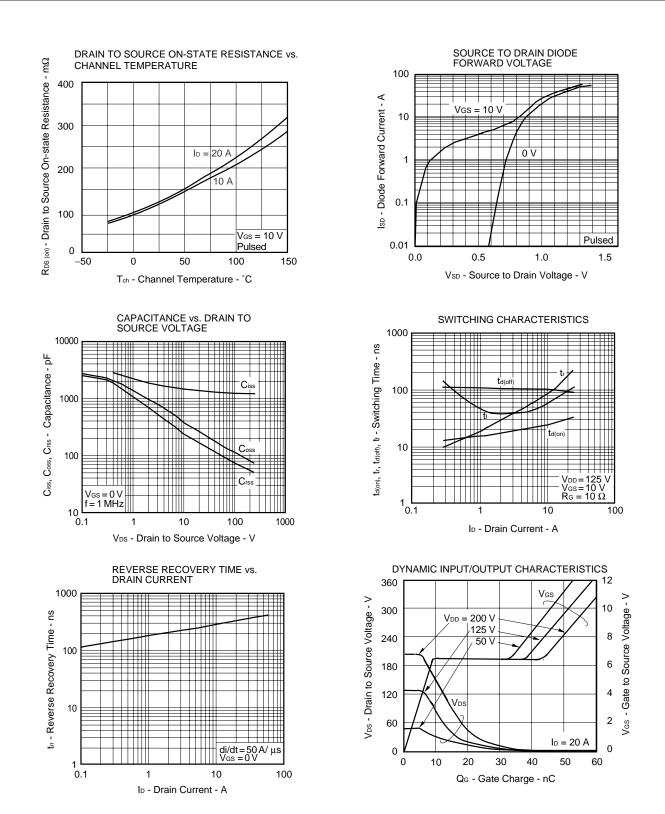


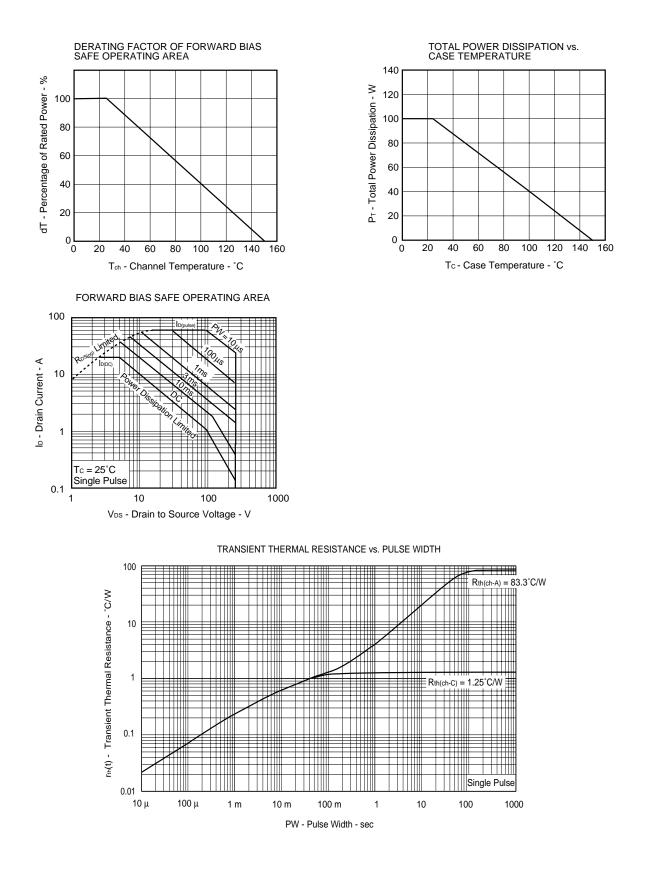


TYPICAL CHARACTERISTICS (TA = 25°C)

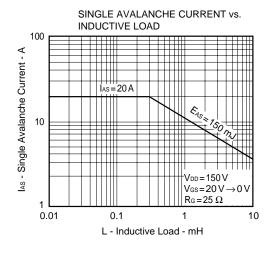


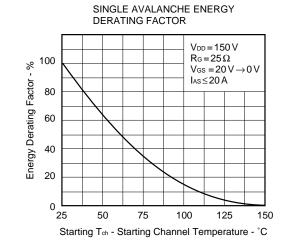






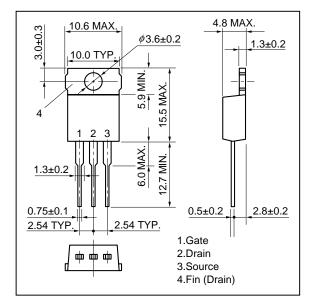
Data Sheet D14061EJ1V0DS



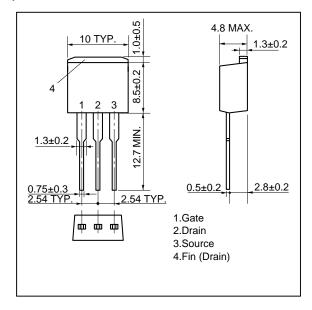


PACKAGE DRAWINGS (Unit: mm)

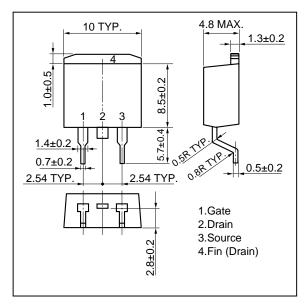
1)TO-220AB (MP-25)



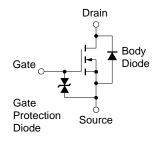
2)TO-262



3)TO-263 (MP-25ZJ)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

• The information in this document is current as of August, 2001. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products and/or types are available in every country. Please check with an NEC sales representative for availability and additional information.

- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC semiconductor products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software and information in the design of customer's equipment shall be done under the full responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize risks of damage to property or injury (including death) to persons arising from defects in NEC semiconductor products, customers must incorporate sufficient safety measures in their design, such as redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:

"Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of a semiconductor product depend on its quality grade, as indicated below. Customers must check the quality grade of each semiconductor product before using it in a particular application.

- "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
- "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
- "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.

(Note)

(1) "NEC" as used in this statement means NEC Corporation and also includes its majority-owned subsidiaries.

(2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).